Voltage monitoring IC with protection IC MW3793 Series

Outline

The MW3793 is a voltage monitoring IC with a function of the protection IC for lithium ion batteries. For a solution including a charge circuit, the MW3793 on the battery pack realizes accurate measurement of the battery voltage. This solution can maximize the CC (constant current) charge mode of the charge circuit, and reduce the charge. As a communication interface, MIPI® BIF, which is a battery interface developed by MIPI® Alliance (an international organization), is used.

Features

| (1) 0V battery charge function permission or inhibition | inhibition 1.50V | Accuracy±0.10V |
|---|---------------------|-----------------|
| (2) High accuracy of voltage detection circuit | | |
| Overcharge detection voltage | 4.425V | Accuracy±0.020V |
| Overdischarge detection voltage | 2.450V | Accuracy±0.035V |
| Discharge overcurrent detection voltage | 34.0mV | Accuracy±5.0mV |
| Charge overcurrent detection voltage | –22.0mV | Accuracy±3.3mV |
| Short detection voltage1 | 80.0mV | Accuracy±9.0mV |
| (3) Low current consumption | | |
| (4) Protection mode latch function | | |
| ●Overcharge | Disable | |
| ●Overdischarge | Disable | |
| Discharge overcurrent | Disable | |
| ●Charge overcurrent | Enable | |
| (5) Communication method. MIPI® BIF complian | nt | |

Applications

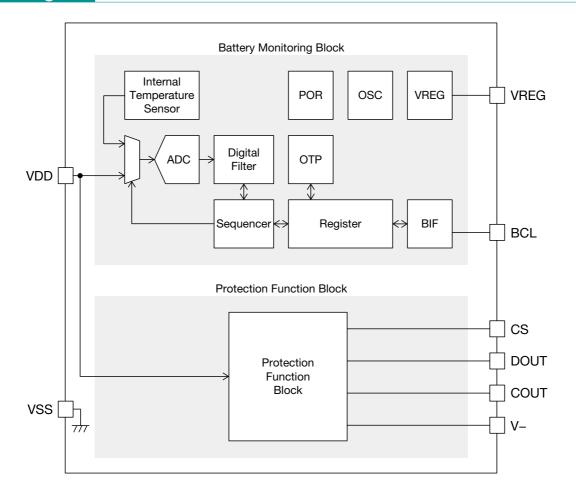
Voltage monitoring, Li-ion battery protection

Pin Assignment

| Top view PLP-8H | Pin No. | Symbol | IN/OUT | Function |
|--------------------|---------|--------|--------|--|
| | 1 | VSS | | VSS terminal |
| | 2 | VREG | OUT | Regulator output terminal |
| | 3 | VDD | IN | VDD terminal |
| 2 7 | 4 | BCL | IN/OUT | BCL terminal for BIF communication |
| 3] [6] | 5 | DOUT | OUT | Discharge FET control terminal |
| 4 | 6 | COUT | OUT | Charge FET control terminal |
| | 7 | V– | IN | Negative power supply voltage input terminal |
| | 8 | CS | IN | Current detection terminal |

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Block Diagram

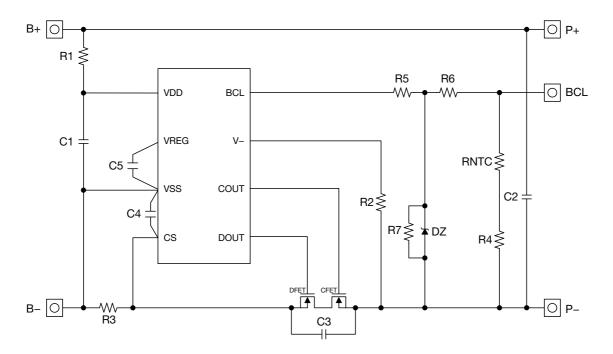


Product Line up

| Product name | Package | A A Overcharge detection 11 voltage | A A Voltage | A A Overdischarge detection 72 voltage | A.A. Coverdischarge release Nottage | Discharging overcurrent Detection voltage | A A A A Charging overcurrent A A<th> Short detection voltage 1 </th><th> Short detection coltage 2 </th> | Short detection voltage 1 | Short detection coltage 2 |
|--------------|---------|--|--|---|---|--|---|--|--|
| MW3793MT1RRE | PLP-8H | 4.425 | 4.225 | 2.450 | 2.800 | 0.034 | -0.022 | 0.080 | VDD-0.9 |
| MW3793MT4RRE | PLP-8H | 4.475 | 4.275 | 2.450 | 2.800 | 0.034 | -0.028 | 0.080 | VDD-0.9 |
| MW3793MT5RRE | PLP-8H | 4.425 | 4.225 | 2.450 | 2.800 | 0.035 | -0.035 | 0.080 | VDD-0.9 |

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Application Circuit



| Symbol | Part | Min. | Тур. | Max. | Purpose |
|--------------|-------------|------|------------------------|------------------------|--|
| R1 | Resistor | | 10Ω | | For voltage fluctuation, For ESD |
| R2 | Resistor | | $1.0 \mathrm{k}\Omega$ | $1.0 \mathrm{k}\Omega$ | Current limit for charger reverse connection |
| R3 | Resistor | | | $4m\Omega$ | Current detection resistance |
| R4 | Resistor | | $16 k\Omega$ | | ID resistor |
| R5 | Resistor | | 100Ω | 100Ω | For ESD |
| R6 | Resistor | | 100Ω | 100Ω | For ESD |
| R7 | Resistor | | $1M\Omega$ | $1M\Omega$ | Pull-down resistor |
| RNTC | Thermistor | | $10 \mathrm{k}\Omega$ | | Thermistor |
| C1 | Capacitor | | 1.0µF | | For voltage fluctuation |
| C2 | Capacitor | | 0.1µF | | For exogenous noise |
| C3 | Capacitor | | 0.1µF | | For exogenous noise |
| C4 | Capacitor | | 0.1µF | | For exogenous noise |
| C5 | Capacitor | | 0.1µF | | For internal voltage regulator fluctuation |
| DZ | Zener Diode | | 6.8V | | ESD protection diode |
| DFET CFET | Nch MOS FET | | $5 \mathrm{m}\Omega$ | | Charge and discharge control |

This typical application circuit and constant value do not guarantee proper operation. Please evaluate thoroughly by actual application to set up constants.

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Precautions for safe handling

- R1 and C1 stabilize a supply voltage fluctuation. However, the detection voltage of protection operation rises and voltage sensor error of voltage monitor function increases by the current consumption of IC when R1 is too large. Therefore, R1 should be 10ohm. Please use 1.0µF for C1 to stabilize the operation.
- R1 and R2 resistors are current limit resistance if a charger is connected reversely or a high-voltage charger that exceeds the absolute maximum rating is connected. If "R1+R2" is too small, the power consumption have potential to exceeding the allowed power dissipation of IC, and "R1 and R2" should be more than 1kohm. R2 should be 1kohm as well.
- · In the over discharge mode, V- terminal is pulled up to VDD by Rpu. If a charger is connected, P- terminal is dropped to about -0.7V by parasitical Di of DFET. And Iv- flows from P+ to P- terminal and the voltage drop (\triangle VR1) arises in R1. Therefore, the cell voltage (Vrel2') at overdischarge release is expressed in the following equation.

Vrel2' = Vdet2 + ⊿VR1 = Vrel2 + R1 *Iv-= Vrel2 + R1 * (Vdet2 + 0.7) / (R1 + Rpu + R2)

- C2 and C3 have effect of stabilizing the system by improving the capacity for voltage ripples and exogenous noises. Please decide the necessity of insertion, position, and capacitance value in consideration of the system characteristic.
- · If R3 is too large, the power loss increases. Moreover, the power consumption might exceed the allowable power dissipation of resistance by the overcurrent. Please select R3 according to the cell and system spec.
- · C4 capacitors will improve the tolerated capacity for exogenous noise and prevent false discharge overcurrent detection. Please arrange C4 near the CS and VSS terminal.
- · Current thresholds of discharging overcurrent detection and short detection (Idoc, Ishort) are expressed in the following equations.

Idoc = Vdet3 / R3 Ishort1 = Vshort1 / R3 Ishort2 = Vshort2 / (R3 + 2Ron) *Ron : ON resistance of CFET and DFET

- \cdot Current threshold of charging overcurrent detection (lcoc) is expressed in the following equation. lcoc = -Vdet4 / R3
- \cdot R4 and RNTC are an ID resistor and a thermistor for a set device, respectively.
- C5 is a capacitor stabilizing the internal regulator operation of the MW3793. The sensors, AD converter, and logic circuit of the MW3793 are designed on the assumption that the internal regulator supplies exactly 1.8V to them. Hence it's necessary to connect the capacitor with VREG pin which is output pin of the internal regulator voltage to guarantee the accuracy of the voltage sensor and temperature sensor. The capacitance value of C5 shall be 0.1µF.
- · R5 is a limiting resistor of ESD serge which is input to zenor diode (DZ) and the MW3793. R5 limits the electric current when ESD serge is applied.
- R6 is a limiting resistor of ESD serge input to the MW3793. R6 limits the electric current that the zenor diode cannot remove when ESD serge is applied.
- \cdot DZ is a device protecting communication terminal from ESD.
- R7 is an optional pull-down resistor. The resistor ensures that the BCL is pulled down to GND when BCL line is not pulled up by the external circuit, for example when the battery pack is not connected to a host device. If RNTC and RID are connected between BCL and GND, the R7 is unnecessary as the RNTC and RID work as pull-down resistors.

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